

L Number	Hits	Search Text	DB	Time stamp
1	21	ring adj gate and source and drain and (field adj oxide or fox or sti)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/06 08:31
14	9	(mosfet or misfet or fet or nmos or pmos or cmos or mos) and (channel) near3 (chain or multiple) near2 implant	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/06 08:37
-	52	(floating near ring) and gate and source and drain	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/06 08:36
-	2	6670685.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/02 14:11
-	3	("6127709" "6384462" "6468837" "2003/0025154").PN.	USPAT	2004/07/02 13:52
-	1306	(field adj oxide or sti or fox) with (between or spacing or separating) with (gate) with (source or drain)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/02 14:12
-	155	(field adj oxide or sti or fox) near5 (between or spacing or separating) near3 (gate) near3 (source or drain)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/02 15:01
-	9	("5406110" "5514608" "5627394" "5846866" "6160290" "6252278" "6424005" "6468837" "6521946").PN.	USPAT	2004/07/02 14:25
-	37	ring near gate and source and drain and (field adj oxide or fox or sti)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/02 15:10
-	148	ring near2 gate and ring near3 (guard or implant or implanted or doped or doping or floating)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/02 15:24
-	3	("6127709" "6384462" "6468837" "2003/0025154").PN.	USPAT	2004/07/02 15:15
-	106	(edmos or demos) and (field adj oxide or field adj insulat\$ or fox or sti)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/02 15:35
-	5359	(edmos or demos or hvmos or hvnmos or hvpmos or hv near mos or ed near mos or edfet or edmosfet or ed adj mosfet or fet or mos or transistor) and (backgate or back adj gate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/02 15:36
-	719	(edmos or demos or hvmos or hvnmos or hvpmos or hv near mos or ed near mos or edfet or edmosfet or ed adj mosfet or fet or mos or transistor) and (backgate or back adj gate) and (field adj oxide or fox or sti or trench near isolation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/02 15:37
-	686	(edmos or demos or hvmos or hvnmos or hvpmos or hv near mos or ed near mos or edfet or edmosfet or ed adj mosfet or fet or mos or transistor) and (backgate or back adj gate) and (field adj oxide or fox or sti or trench near isolation) and source and drain	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/02 15:38

-	7	(edmos or demos or hvmos or hvnmos or hvpmos or hv near mos or ed near mos or edfet or edmosfet or ed adj mosfet) and (backgate or back adj gate) and (field adj oxide or fox or sti or trench near isolation) and source and drain	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/02 15:38
-	10	(edmos or demos or hvmos or hvnmos or hvpmos or hv near mos or ed near mos or edfet or edmosfet or ed adj mosfet) and (backgate or back adj gate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/02 15:39
-	2756	source and gate and drain and (field adj oxide or fox or sti or trench near isolation) near4 (implant or implanted or doped or doping or dopant or impurity or implanting)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/02 15:40
-	774	source and gate and drain and (field adj oxide or fox or sti or trench near isolation) near4 (implant or implanted or doped or doping or dopant or impurity or implanting) near3 (adjacent or under or underneath or below or aligned or lower or beneath or above or over or on adj top or higher)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/02 15:41
-	58	(extended near drain or resurf) with (oppositely or opposite or opposing or complimentary or different) with (doped or doping or impurity or dopant or implant or implanted or implanting)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/02 15:50
-	2	6222235.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/02 15:56
-	5	6222235.URPN.	USPAT	2004/07/02 15:50
-	5	("4079407" "5257095" "5374836" "5407852" "5646435").PN.	USPAT	2004/07/02 15:51
-	80	(mos or mosfet) and (floating near ring)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/02 15:56